## Docket No.: 20402-00642-US

## AMENDMENTS TO THE CLAIMS

## LISTING OF CLAIMS

Claims 1-12 (Cancelled)

13. (Previously Amended) A method of manufacturing a pressure transducer comprising the steps of:

preparing a substrate having a first surface and a second surface opposed to the first surface;

forming a fixed electrode in the first surface of said substrate;

forming a sacrificial layer over said fixed electrode;

forming a diaphragm layer made of an insulating material over said sacrificial layer;

forming a hole which extends from the second surface of said substrate to said sacrificial layer;

injecting gasses into said hole to remove said sacrificial layer in dry etching to form a cavity so that said diaphragm layer is deformed in response to an applied pressure; and

forming at least one waved portion on the first surface of said substrate.

14. (Previously Amended) A method of manufacturing a pressure transducer comprising the steps of:

preparing a substrate having a first surface and a second surface opposed to the first surface;

forming a fixed electrode in the first surface of said substrate;

forming a sacrificial layer over said fixed electrode;

forming a diaphragm layer made of an insulating material over said sacrificial layer;

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forming a hole which extends from the second surface of said substrate to said sacrificial layer;

injecting gasses into said hole to remove said sacrificial layer in dry etching to form a cavity so that said diaphragm layer is deformed in response to an applied pressure; and

forming at least one waved portion on a surface of said sacrificial layer.

- 15. (Previously Amended) A method as set forth in claim 13 or 14, wherein said substrate is made of a semiconductor substrate having integrated circuit elements which form a detector designed to measure a capacitance between the fixed and moving electrodes.
- 16. (Previously Amended) A method as set forth in claim 13 or 14, wherein said diaphragm is made of an inorganic material, and said sacrificial layer is made of an organic material.
- 17. (Previously Amended) A method as set forth in claim 13 or 14, wherein said diaphragm is made from a compound of silicon and one of oxygen and nitrogen.
- 18. (Previously Amended) A method as set forth in claim 13 or 14, wherein said sacrificial layer is made of polyimide.
- 19. (Previously Amended) A method as set forth in claim 13 or 14, wherein the removal of said sacrificial layer is achieved in the dry etching using oxygen plasma.
- 20. (Previously Amended) A method as set forth in claim 13 or 14, wherein said gas injecting step removes said sacrificial layer so as to leave a peripheral portion of said sacrificial layer.

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21. (Original) A method of manufacturing a pressure transducer comprising the steps of:

preparing a substrate having a first surface and a second surface opposed to the first surface;

forming a fixed electrode in the first surface of said substrate;

forming an insulating layer over said fixed electrode;

forming a sacrificial layer on said insulating layer;

forming a diaphragm layer made of a conductive material over said sacrificial layer;

forming a hole which extends from the second surface of said substrate to said sacrificial layer; and

injecting gasses into said hole to remove said sacrificial layer in dry etching to form a cavity so that said diaphragm layer is deformed in response to an applied pressure.

- 22. (Original) A method as set forth in claim 21, further comprising the step of forming at least one waved portion on the first surface of said substrate.
- 23. (Original) A method as set forth in claim 21, further comprising the step of forming at least one waved portion on a surface of said sacrificial layer.
- 24. (Original) A method as set forth in claim 21, wherein said substrate is made of a semiconductor substrate having integrated circuit elements which form a detector designed to measure a capacitance between the fixed and moving electrodes.
- 25. (Original) A method as set forth in claim 21, wherein said diaphragm is made of an inorganic material, and said sacrificial layer is made of an organic material.

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26. (Previously Amended) A method as set forth in claim 21 wherein said diaphragm is made from a compound of silicon and one of oxygen and nitrogen.

- 27. (Original) A method as set forth in claim 21, wherein said sacrificial layer is made of polyimide.
- 28. (Original) A method as set forth in claim 21, wherein the removal of said sacrificial layer is achieved in the dry etching using oxygen plasma.
- 29. (Original) A method as set forth in claim 21, wherein said gas injecting step removes said sacrificial layer so as to leave a peripheral portion of said sacrificial layer.
- 30. (Canceled).